

ES8J

8.0AMPS. SUPER FAST SURFACE MOUNT RECTIFIER

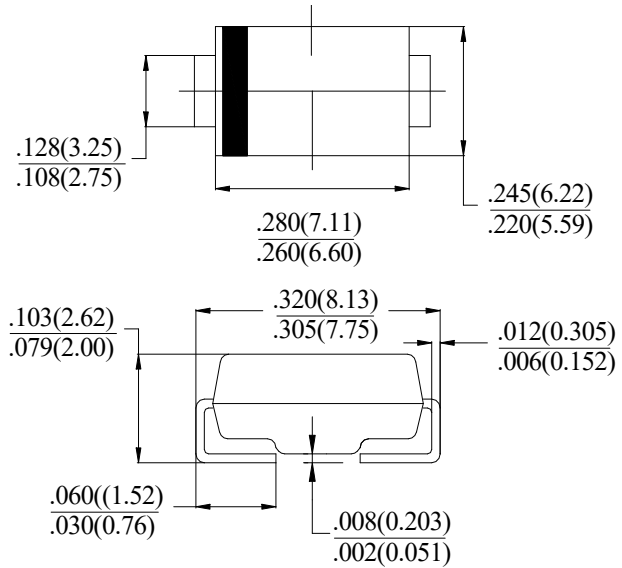
FEATURE

- . High current capability
- . Low forward voltage drop
- . Low power loss, high efficiency
- . High surge capability
- . High temperature soldering guaranteed
260°C/10 seconds at terminals.
- . Superfast recovery time for high efficiency
- . For surface mounted application.
- . Easy pick and place.

MECHANICAL DATA

- . Case: Molded plastic
- . Epoxy: UL94V-0 rate flame retardant
- . Lead: MIL-STD- 202E, Method 208 guaranteed
- . Polarity:Color band denotes cathode end
- . Mounting position: Any

SMC (DO-214AB)



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%

Type Number	SYM BOL	ES8J	units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	600	V
Maximum RMS Voltage	V_{RMS}	420	V
Maximum DC blocking Voltage	V_{DC}	600	V
Maximum Average Forward Rectified Current	$I_{F(AV)}$	8.0	A
Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	I_{FSM}	150.0	A
Maximum Forward Voltage at 8.0A DC	V_F	1.9	V
Maximum DC Reverse Current @ $T_J=25^{\circ}C$ at rated DC blocking voltage @ $T_J=125^{\circ}C$	I_R	5.0 200.0	μA
Maximum Reverse Recovery Time (Note 1)	t_{rr}	50	nS
Typical Junction Capacitance (Note 2)	C_J	40	pF
Typical Thermal Resistance (Note 3)	$R_{(JA)}$	55	$^{\circ}C/W$
	$R_{(JC)}$	15	
Storage Temperature	T_{STG}	-55 to +150	$^{\circ}C$
Operation Junction Temperature	T_J	-55 to +150	$^{\circ}C$

Note:

1. Reverse Recovery test Condition: $I_f=0.5A, I_R=1.0A, I_{RR}=0.25A$
2. Measured at 1.0 MHz and applied reverse voltage of 4.0Vdc
3. P.C.B.Mounted on $0.6 \times 0.6'' (15.0 \times 15.0mm)$ Copper Pad Area.

RATING AND CHARACTERISTIC CURVES

FIG.1-TYPICAL FORWARD CURRENT DERATING CURVE

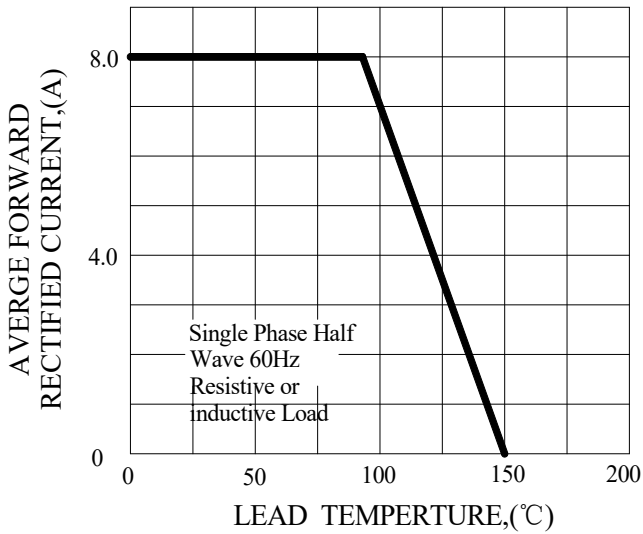


FIG.2-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

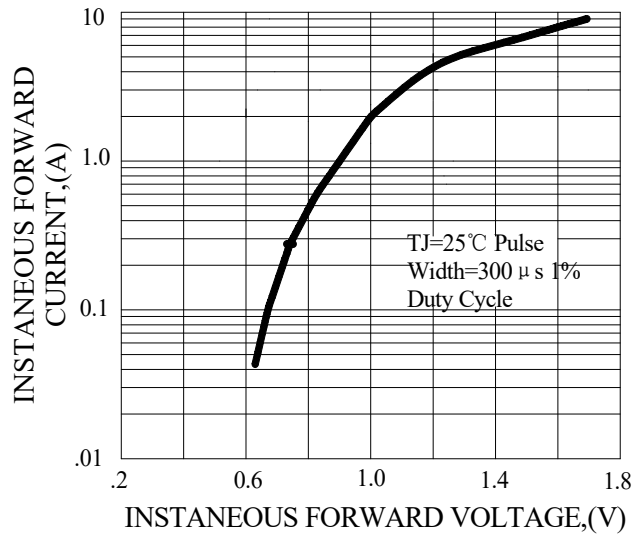


FIG.3-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

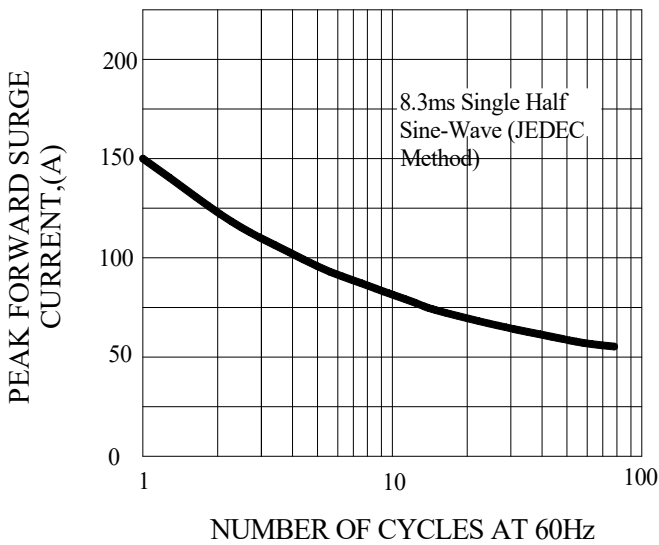


FIG.4-TYPICAL REVERSE CHARACTERISTICS

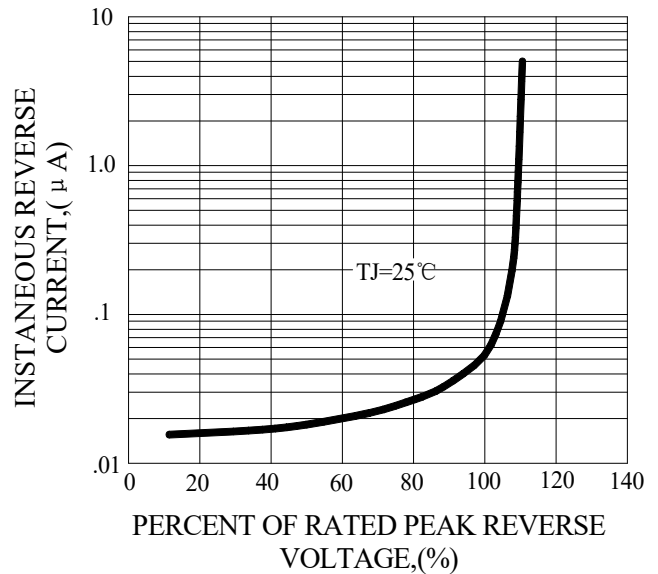
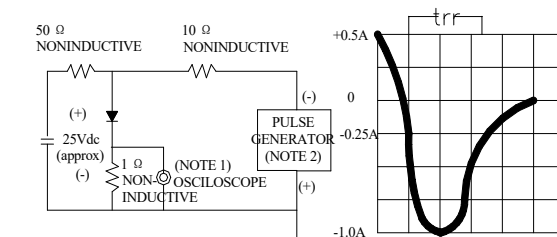
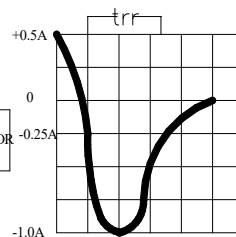


FIG.5-TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC

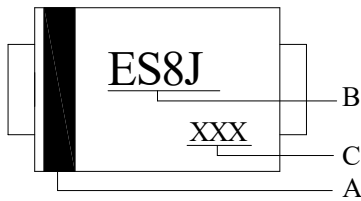


NOTES:1. Rise Time=7ns max, Input Impedance= 1 megohm.22pF.
2. Rise Time=10ns max, Source Impedance= 50 ohms.



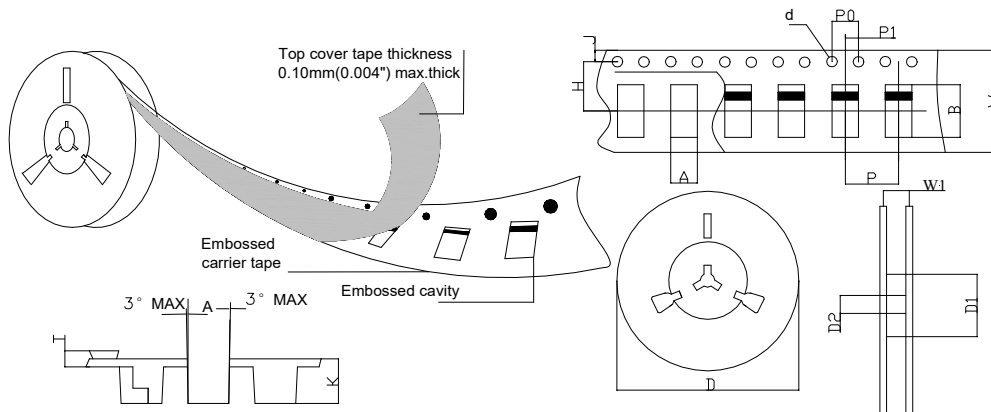
Marking and packaging illustration

1、Marking



SYMBOL	Explanation
A	Color Band Denotes Cathode
B	Product Name
C	Date code

2、Packaging



SPECIFICATIONS mm(inch)		PACKAGE	SPECIFICATIONS mm(inch)		PACKAGE
ITEM	SYM BOL	DO-214AB	ITEM	SYM BOL	DO-214AB
Carrier width	A	6.15(0.242)Max	Carrier depth	K	2.54(0.100)Typ
Carrier length	B	8.41(0.331)Max	Punch hole pitch	P	8.00(0.315)Typ
Sprocket hole	d	ø1.55(0.061)Typ	Sprocket hole pitch	P0	4.00(0.157)Typ
Reel outer diameter	D	330.0(13.0)Typ	Embossment center	P1	2.00(0.079)Typ
Reel inner diameter	D1	74.0(2.913)Min	Overall tape thickness	T	0.25(0.010)Typ
Feed hole diameter	D2	13.0(0.512)Typ	Tape width	W	16.0(0.430)Typ
Sprocket hole position	J	1.75(0.069)Typ	Reel width	W1	16.5(0.650)Min
Punch hole position	H	7.50(0.295)Typ			